

EOP400-DR4+

400Gb/s OSFP112 2KM DDM Transceiver

PRODUCT FEATURES

- OSFP form factor hot pluggable
- CMIS compliance
- 4 parallel lanes of 100G-PAM4 electrical and optical parallel lanes
- Optical port of MPO-12/APC
- Up to 2km transmission
- 9 Watts max
- Case temperature range of 0 to 70 °C

The transceiver complies with common management interface specification (CMIS). The supported key features listed below allow host software to read and control the transceiver status through I2C.

- Adaptive Tx input equalization
- Programmable Rx output amplitude
- Programmable Rx output pre-cursor
- Programmable Rx output post-cursor
- Supply voltage monitoring (DDM_Voltage)
- Transceiver case temperature monitoring (DDM_Temperature)
- Tx transmit optical power monitoring for each lane (DDM_TxPower)
- Tx bias current monitoring for each lane (DDM_TxBias)
- Rx receive optical power monitoring for each lane (DDM_RxPower)
- Warning and alarm indication for each DDM function
- Tx & Rx LOL and LOS indication
- Tx fault indication
- Host and line side loopback capabilities
- Host and line side PRBS generator and checker capabilities
- CDB firmware upgrade capability
- Versatile diagnostics monitoring (VDM) capability (optional, additional power consumption increase)
- Other functions defined in CMIS

APPLICATIONS

The transceiver is designed for Ethernet, Telecom and Infiniband use cases. The application advertisements listed below allow host software to select proper application following CMIS definition

Table 1 shows CMIS application advertisements list:

ApSel Code	Host Electrical Interface	Module Media Interface	Host and Media Lane Count	Host Lane Assignment
ApSel 1	4C (100GAUI-1-L C2M)	14 (100GBASE-DR)	11 (1:1)	0F (lanes 1,2,3,4)
ApSel 2	50 (400GAUI-4-L C2M)	1C (400GBASE-DR4)	44 (4:4)	01 (lanes 1)
ApSel 3	4B (100GAUI-1-S C2M)	14 (100GBASE-DR)	11 (1:1)	0F (lanes 1,2,3,4)
ApSel 4	4F (400GAUI-4-S C2M)	1C (400GBASE-DR4)	44 (4:4)	01 (lanes 1)

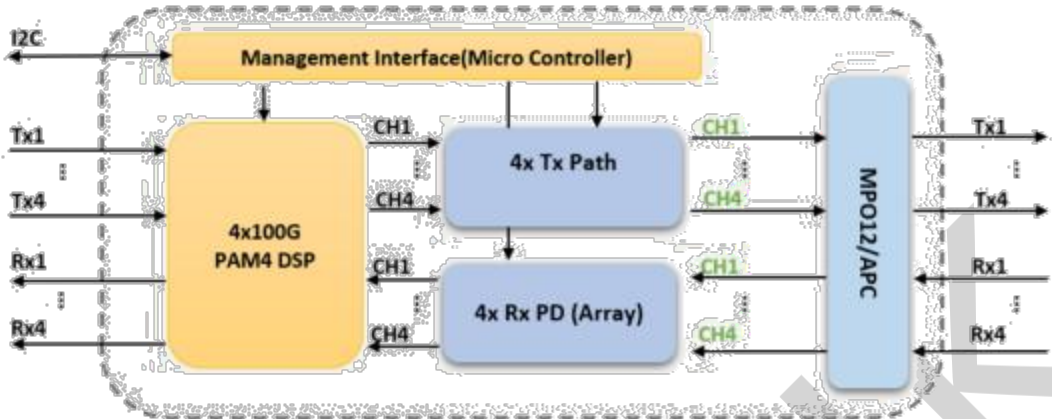
DESCRIPTIONS

This product is an 400Gb/s Octal Small Form-factor Pluggable (OSFP) optical module without top open fin designed for 2km optical communication applications. The module converts 4 channels of 100Gb/s (PAM4) electrical input data to 4 channels of parallel optical signals, each capable of 100Gb/s operation for an aggregate data rate of 400Gb/s. Reversely, on the receiver side, the module converts 4 channels of parallel optical signals of 100Gb/s each channel for an aggregate data rate of 400Gb/s into 4 channels of 100Gb/s (PAM4) electrical output data.

One MPO-12 connector can be plugged into the OSFP112 DR4+ module jack with 4 channels. Proper alignment is ensured by the guide pins inside the receptacle. The cable usually cannot be twisted for proper channel to channel alignment. Electrical connection is achieved through an OSFP MSA-compliant edge type connector.

I2C interface is supported to read and control the status of this product.

Module Block Diagram



Ordering Information

Part Number	Description
EOP400-DR4+	400G OSFP112 DR4+ transceiver, single MPO-12 connector, 4 parallel lanes, up to 2km, with pull tab, RHS OSFP

Absolute Maximum Ratings

It has to be noted that the operation in excess of any individual absolute maximum ratings might cause permanent damage to this module.

Parameter	Symbol	Min	Max	Units	Notes
Storage Temperature	TS	-40	85	degC	
Operating Case Temperature	TOP	0	70	degC	
Power Supply Voltage	VCC	-0.5	3.6	V	
Relative Humidity (non-condensation)	RH	0	85	%	

Recommended Operating Conditions

Parameter	Symbol	Min	Typical	Max	Units	Notes
Operating Case Temperature	TOP	0		70	degC	
Power Supply Voltage	VCC	3.135	3.3	3.465	V	
Data Rate, each Lane			53.125		GBd	PAM4
Data Rate Accuracy		-100		100	ppm	
Pre-FEC Bit Error Ratio				2.4x10 ⁻⁴		
Post-FEC Bit Error Ratio				1x10 ⁻¹²		1
Link Distance	D	0.002		2	km	2

Notes:

1. FEC provided by host system.
2. FEC required on host system to support maximum distance.

Electrical Characteristics

The following electrical characteristics are defined over the Recommended Operating Environment unless otherwise specified.

Parameter	Test Point	Min	Typical	Max	Units	Notes
Power Consumption				9	W	
Supply Current	I _{cc}			2.72	A	
Module Input (each Lane)						
Signaling Rate, each Lane	TP1	53.125 ± 100 ppm			GBd	
DC Common-mode input Voltage	TP1	-0.35		2.85	V	
Single-ended input Voltage	TP1a	-0.4		3.3	V	
AC Common-mode RMS input Voltage	TP1a				mV	
Low-Frequency, VCMLF		32				
Full-Band, VCMLF		80				
Module stressed input test		IEEE 802.3ck 120G3.4.3				
Differential Peak-to-Peak input Voltage tolerance	TP1a	750			mV	

Common to Different Mode input Return Loss	TP1	IEEE802.3ck Equation 120G-2				
Effective input Return Loss	TP1	8.5			dB	
Differential input Termination Mismatch	TP1			10	%	
Receiver (each Lane)						
Signaling Rate, each lane	TP4	53.125 ± 100 ppm			GBd	
Differential Peak-to-Peak Output Voltage Short Mode Long Mode	TP4			600 845	mV	
AC Common Mode Output Voltage, RMS Low-frequency, VCMLF Full-Band, VCMLF	TP4			32 80	mV	
Differential Termination Mismatch	TP4			10	%	
Vertical eye closure, VEC	TP4			12	dB	
Eye Height	TP4	15			mV	
Common-mode to Differential mode output Return Loss	TP4	IEEE802.3ck Equation 120G-1			dB	
Effective output Return Loss	TP4	8.5			dB	
Output Transition time (20% to 80%)	TP4	8.5			ps	
DC Common-mode output Voltage	TP4	-350		2850	mV	

Optical and Characteristics

Parameter	Symbol	Min	Typical	Max	Units	Notes
Wavelength	λ	1304.5	1310	1317.5	nm	
Transmitter						
Data Rate, each Lane		53.125 \pm 100 ppm			GBd	
Modulation Format		PAM4				
Side-mode Suppression Ratio	SMSR	30			dB	
Average Launch Power, each Lane	PAVG	-3.1		4	dBm	1
Outer Optical Modulation Amplitude (OMA _{outer}), each Lane For TDECQ < 1.4dB For 1.4 \leq TDECQ \leq 3.4dB	POMA	-0.1 -1.5+TDECQ		4.2	dBm	2
Transmitter and Dispersion Eye Closure for PAM4 (TDECQ), each Lane	TDECQ			3.4	dB	
TDECQ-TECQ				2.5	dB	
Over/Undershoot				22	%	
Transmitter power excursion				2	dBm	
Extinction Ratio	ER	3.5			dB	
Transition time	Tt			17	ps	
RIN _{17.1OMA}	RIN			-136	dB/Hz	
Optical Return Loss Tolerance	TOL			17.1	dB	
Transmitter Reflectance	RT			-26	dB	
Average Launch Power of OFF Transmitter, each Lane	P _{off}			-15	dBm	
Receiver						
Data Rate, each Lane		53.125 \pm 100 ppm			GBd	

Modulation Format		PAM4				
Damage Threshold, each Lane	THd	5			dBm	3
Average Receive Power, each Lane		-7.1		4	dBm	4
Receive Power (OMA _{outer}), each Lane				4.2	dBm	
Receiver Sensitivity (OMA _{outer}),each Lane	SEN			Equation (1)	dBm	5
Stressed Receiver Sensitivity (OMA _{outer}),each Lane	SRS			-2.5	dBm	6
Receiver Reflectance	RR			-26	dB	
LOS Assert	LOSA	-15		-9.1	dBm	
LOS De-assert	LOSD			-8.1	dBm	
LOS Hysteresis	LOSH	0.5			dB	
Conditions of Stress Receiver Sensitivity Test (Note 7)						
Stressed Eye Closure for PAM4 (SECQ), Lane under Test			3.4		dB	

Notes:

- Average launch power, each lane (min) is informative and not the principal indicator of signal strength. A transmitter with launch power below this value cannot be compliant; however, a value above this does not ensure compliance.
- The values for OMA_{outer} (min) vary with TDECQ. Figure 5 illustrates this along with the values for OMA_{outer}(max).
- The receiver shall be able to tolerate, without damage, continuous exposure to a modulated optical input signal having this power level on one lane. The receiver does not have to operate correctly at this input power.
- Average receive power, each lane (min) is informative and not the principal indicator of signal strength. A received power below this value cannot be compliant; however, a value above this does not ensure compliance.
- Receiver sensitivity (OMA_{outer}) is informative and is defined for a transmitter with a value of SECQ up to 3.4 dB. Receiver sensitivity should meet Equation (1), which is illustrated in Figure 1.

$$RS = \max(-4.5, TECQ - 5.9) \text{ dBm} \quad (1)$$
 Where:
 RS is the receiver sensitivity, and
 TECQ is the TECQ of the transmitter used to measure the receiver sensitivity.
- Measured with conformance test signal at TP3 for the BER equal to 2.4×10^{-4} .
- These test conditions are for measuring stressed receiver sensitivity. They are not characteristics of the receiver.

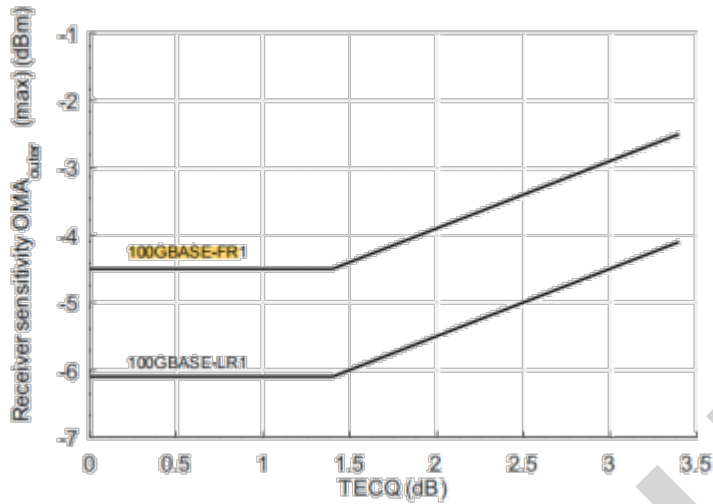


Figure 1. Illustration of Receiver Sensitivity Mask for 100GBASE-FR1

Digital Diagnostics

The following digital diagnostic characteristics are defined over the normal operating conditions unless otherwise specified.

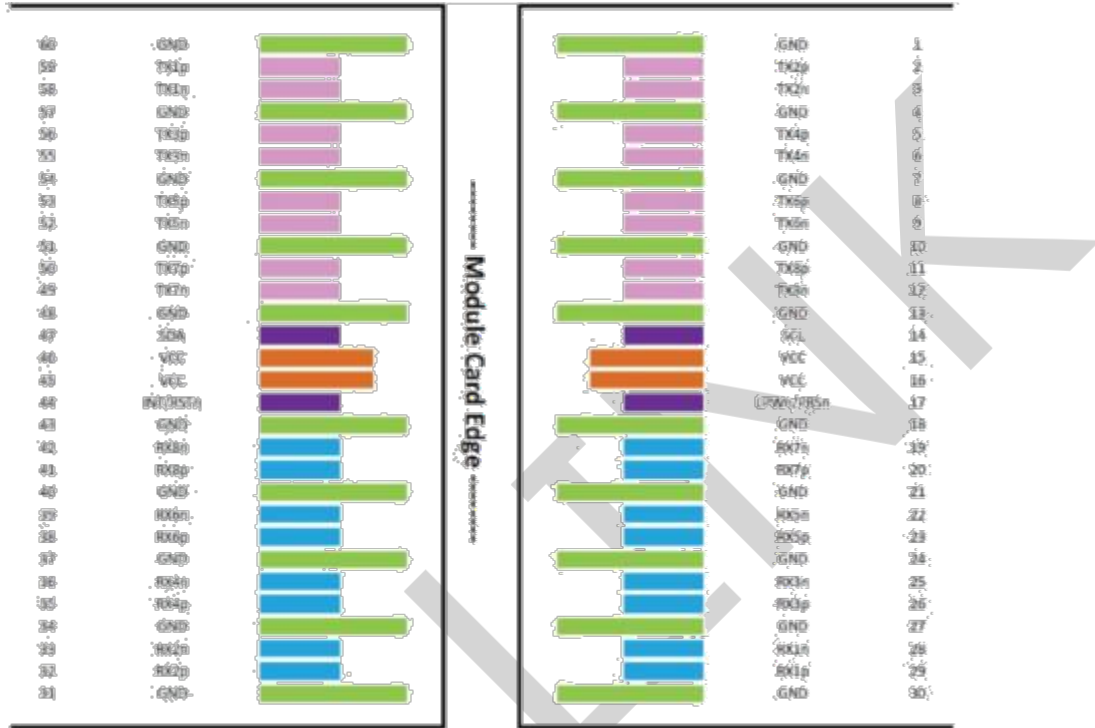
Parameter	Symbol	Min	Max	Units	Notes
Temperature monitor absolute error	DMI_Temp	-3	3	degC	Over operating temperature range
Supply voltage monitor absolute error	DMI_VCC	-0.1	0.1	V	Overfull operating range
Channel RX power monitor absolute error	DMI_RX_Ch	-2	2	dB	1
Channel Bias current monitor	DMI_Ibias_Ch	-10%	10%	mA	
Channel TX power monitor absolute error	DMI_TX_Ch	-2	2	dB	1

Notes:

1. Due to measurement accuracy of different single mode fibers, there could be an additional +/-1 dB fluctuation, or a +/- 3 dB total accuracy.

Pin Diagram

The electrical interface of OSFP module consist of a 60 contacts edge connector as illustrated by the diagram in Figure 2, which defined in Clause 8.1 of OSFP MSA Specification.



Pin Definitions

Pin#	Symbol	Description	Logic	Plug Sequence
1	GND		Ground	1
2	TX2n	Transmitter Data Inverted Input	CML-I	3
3	TX2p	Transmitter Data Non-Inverted Input	CML-I	3
4	GND		Ground	1
5	TX4n	Transmitter Data Inverted Input	CML-I	3
6	TX4p	Transmitter Data Non-Inverted Input	CML-I	3
7	GND		Ground	1
8	ModSelL	Module Select	LVTTL-I	3
9	ResetL	Module Reset	LVTTL-I	3
10	VccRx	+3.3V Power supply receiver		2
11	SCL	2-wire Serial interface clock	LVC MOS-I/O	3
12	SDA	2-wire Serial interface data	LVC MOS-I/O	3
13	GND		Ground	1
14	RX3p	Receiver Data Non-Inverted Output	CML-O	3

15	RX3n	Receiver Data Inverted Output	CML-O	3
16	GND		Ground	1
17	RX1p	Receiver Data Non-Inverted Output	CML-O	3
18	RX1n	Receiver Data Inverted Output	CML-O	3
19	GND		Ground	1
20	GND		Ground	1
21	RX2n	Receiver Data Inverted Output	CML-O	3
22	RX2p	Receiver Data Non-Inverted Output	CML-O	3
23	GND		Ground	1
24	RX4n	Receiver Data Inverted Output	CML-O	3
25	RX4p	Receiver Data Non-Inverted Output	CML-O	3
26	GND		Ground	1
27	ModPrsl	Module Present	LVTTTL-O	3
28	IntL/RxLOS	Interrupt/optional RxLOS	LVTTTL-O	3
29	VccTx	+3.3V Power supply transmitter		2
30	Vcc1	+3.3V Power Supply		2
31	LPMoDe/TxDis	Lower Power Mode/optional TX Disable	LVTTTL-I	3
32	GND		Ground	1
33	TX3p	Transmitter Data Non-Inverted Input	CML-I	3
34	TX3n	Transmitter Data Inverted Input	CML-I	3
35	GND		Ground	1
36	TX1p	Transmitter Data Non-Inverted Input	CML-I	3
37	TX1n	Transmitter Data Inverted Input	CML-I	3
38	GND		Ground	1

Recommended Interface Circuit

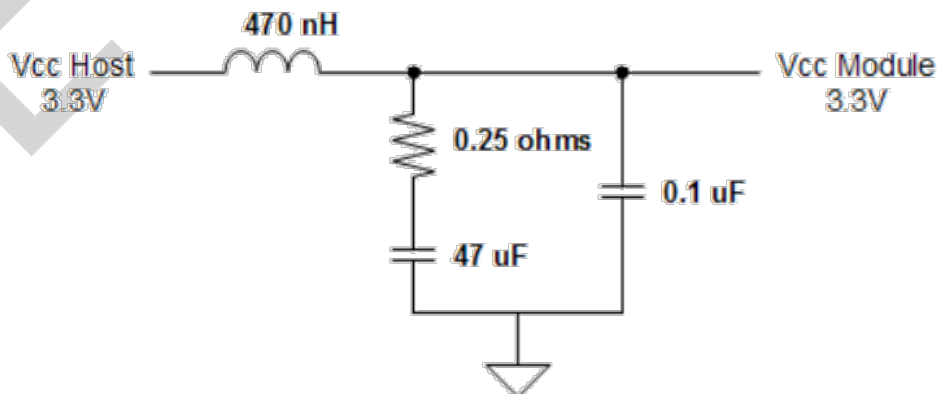
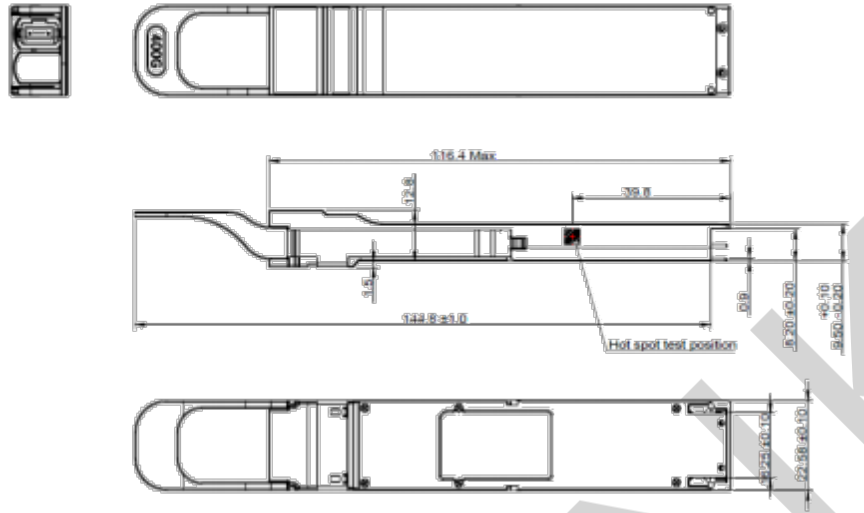


Figure 13-6: Host board power filter circuit

Mechanical Diagram



Notes:

1. The mechanical design is flattop (RHS).
2. The pull tab color is green, engraved with "400G" letter.

Revision History

Version No.	Date	Description
1.0	February 18, 2023	Preliminary datasheet
1.1	August 05, 2024	Format change

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